November 2013



# FGPF50N33BT 330 V PDP Trench IGBT

### **Features**

- High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> =1.6 V @ I<sub>C</sub> = 50 A
- High Input Impedance
- RoHS Compliant

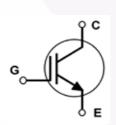
## **General Description**

Using novel trench IGBT technology, Fairchild's new series of trench IGBTs offer the optimum performance for PDP TV applications where low conduction and switching losses are essential.

## Applications

PDP TV





### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit V	
V <sub>CES</sub>	Collector to Emitter Voltage	330			
V <sub>GES</sub>	Gate to Emitter Voltage		± 30	V	
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	50	А	
I <sub>Cpulse (1)*</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	120	A	
I <sub>Cpulse (2)*</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	160	A	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	43	W	
	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	17.2	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	
Τ <sub>L</sub>	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C		

### **Thermal Characteristics**

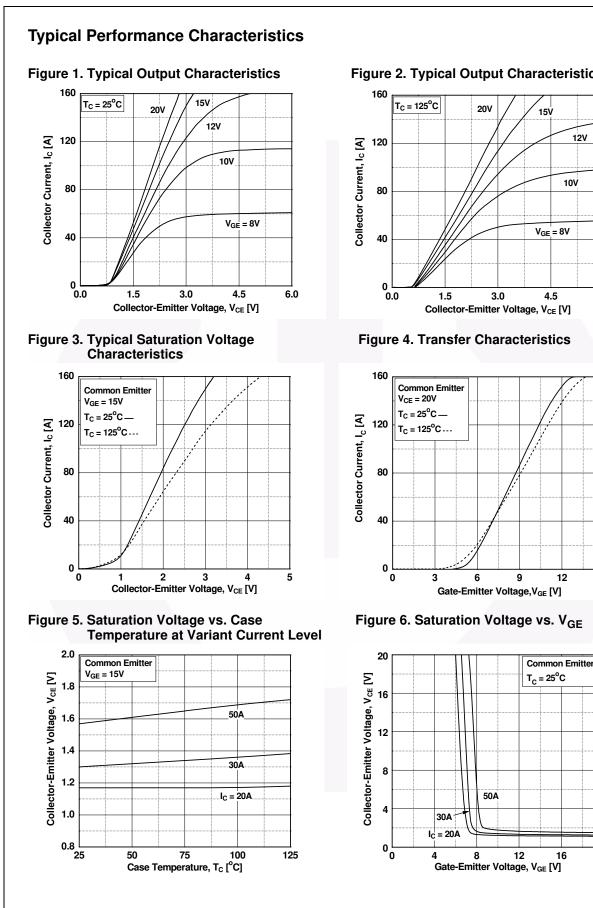
Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	2.9	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

### Notes:

1: Repetitive test , Pulse width=100usec , Duty=0.1 2: Half Sine Wave, D < 0.01, pluse width < 10usec

\*Ic\_pluse limited by max Tj

· · · ·		Top Mark	Package		Packing Method	Reel	Size	Tape Wid	th Qu	Quantity	
		TO-220	DF Tube		N/A		N/A		50		
Electric	al Cha	racteristics of	the IC	GB.	$T_{C} = 25^{\circ}C$ unless otherwise	noted					
Symbol		Parameter			Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristics										
BV <sub>CES</sub>	Collector	r to Emitter Breakdown \	/oltage	V <sub>GE</sub>	= 0 V, I <sub>C</sub> = 250 μA, Tc=	25°C	330	-	-	V	
020			Ū	-	= 0 V, I <sub>C</sub> = 250 μA, Tc=		340	-	-	V	
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage		kdown	$V_{GE} = 0 V, I_C = 250 \mu A$		-	0.2	-	V/ºC		
ICES	Collector	r Cut-Off Current	_	$V_{CE} = V_{CES}, V_{GE} = 0 V, Tc=25^{\circ}C$		25°C	- /	-	20	μA	
			$V_{CE} = V_{CES}$ , $V_{GE} = 0$ V, Tc=125°C		125°C	-	-	200	μA		
I <sub>GES</sub>	G-E Lea	kage Current		V <sub>GE</sub>	$= V_{GES}, V_{CE} = 0 V$		-	-	±200	nA	
On Charac	toristics							•			
V <sub>GE(th)</sub>	G-E Threshold Voltage		-	I <sub>C</sub> =	= 250 μA, V <sub>CE</sub> = V <sub>GE</sub>		2.3	3.3	4.3	V	
CL((II)			-	$I_{\rm C} = 20 \text{ A}, V_{\rm GE} = 15 \text{ V},$		-	1.2	1.5	V		
				I <sub>C</sub> = 30 A, V <sub>GE</sub> = 15 V,		-	1.3	-	V		
V <sub>CE(sat)</sub>			$I_{C} = 50 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 25^{\circ}\text{C}$		-	1.6	-	v			
					50 A, V <sub>GE</sub> = 15 V, = 125°C		-	1.7	-	v	
Dynamic C	haracteri	stics									
C <sub>ies</sub>	1	pacitance					-	980	-	pF	
C <sub>oes</sub>		utput Capacitance		$V_{CE} = 30 V, V_{GE} = 0 V,$		-	70	-	pF		
C <sub>res</sub>				t = 1	f = 1 MHz		-	40	-	pF	
Switching	Characte	ristics							I		
t <sub>d(on)</sub>		Delay Time						9	-	ns	
t <sub>r</sub>	Rise Tim			$V_{CC} = 200$ V, I <sub>C</sub> = 20 A, - R <sub>G</sub> = 5 Ω, V <sub>GE</sub> = 15 V, Resistive Load, T <sub>C</sub> = 25 <sup>o</sup> C			-	33	- /	ns	
t <sub>d(off)</sub>	Turn-Off	Delay Time					-	32	-	ns	
t <sub>f</sub>	Fall Time	9	_		, ·00 0		-	202	-	ns	
t <sub>d(on)</sub>	Turn-On	Delay Time					-	9	-	ns	
t <sub>r</sub>	Rise Tim	le		V <sub>CC</sub> = 200 V, I <sub>C</sub> = 20 A, R <sub>G</sub> = 5 Ω, V <sub>GE</sub> = 15 V, Resistive Load, T <sub>C</sub> = 125 <sup>o</sup> C			-	37	-	ns	
t <sub>d(off)</sub>	Turn-Off	Delay Time					-	33	-	ns	
t <sub>f</sub>	Fall Time	e		1	0	-	-	332	-	ns	
Qg	Total Ga	te Charge		V <sub>CE</sub> = 200 V, I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V			-	35	-	nC	
Q <sub>ge</sub>	Gate to I	Emitter Charge					-	6	-	nC	
Q <sub>gc</sub>	Gate to 0	Collector Charge		▼ GE	10 V		-	14	-	nC	



**Figure 2. Typical Output Characteristics** 

15V

12V

10V

V<sub>GE</sub> = 8V

4.5

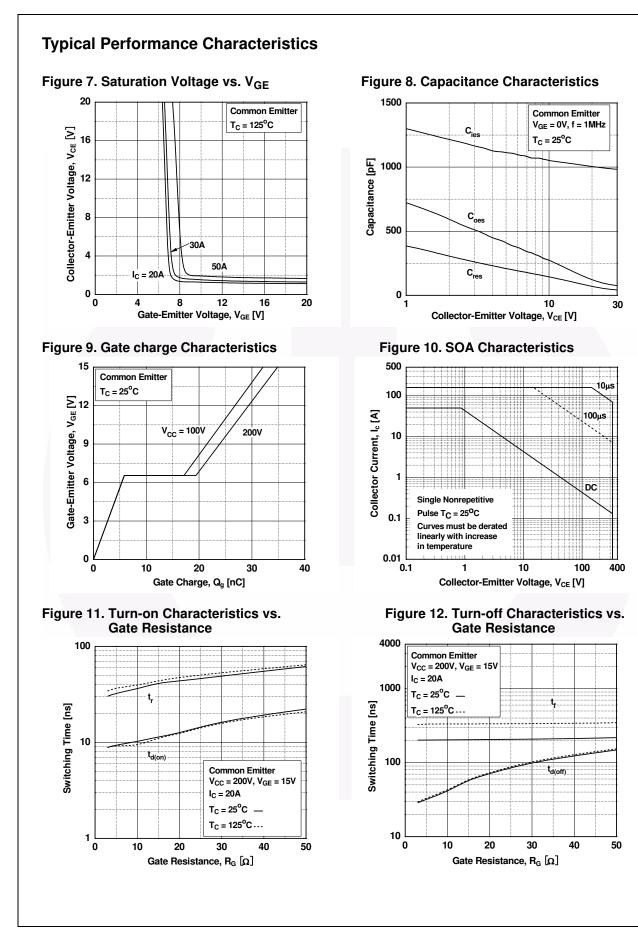
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16

20

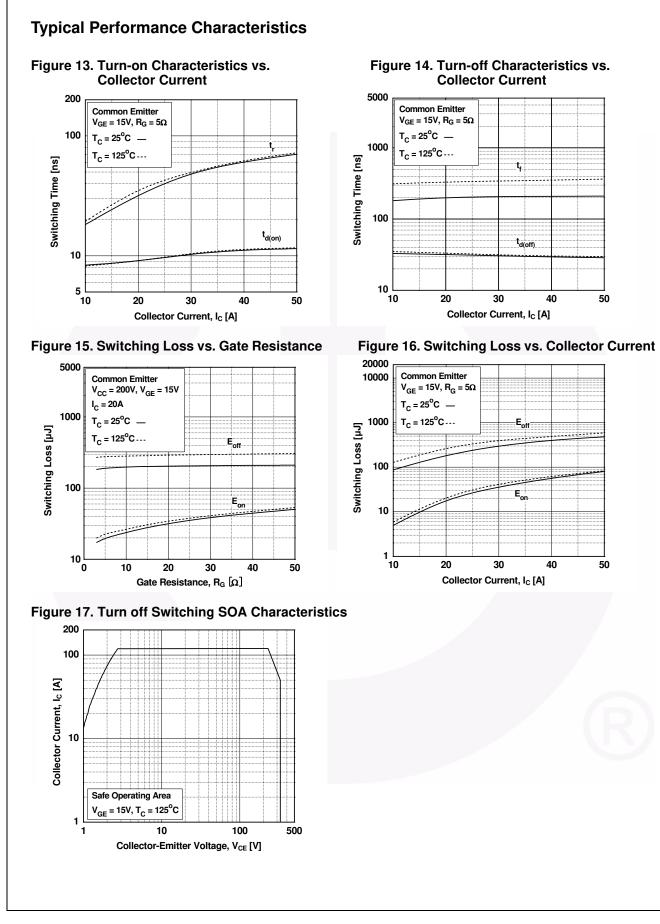
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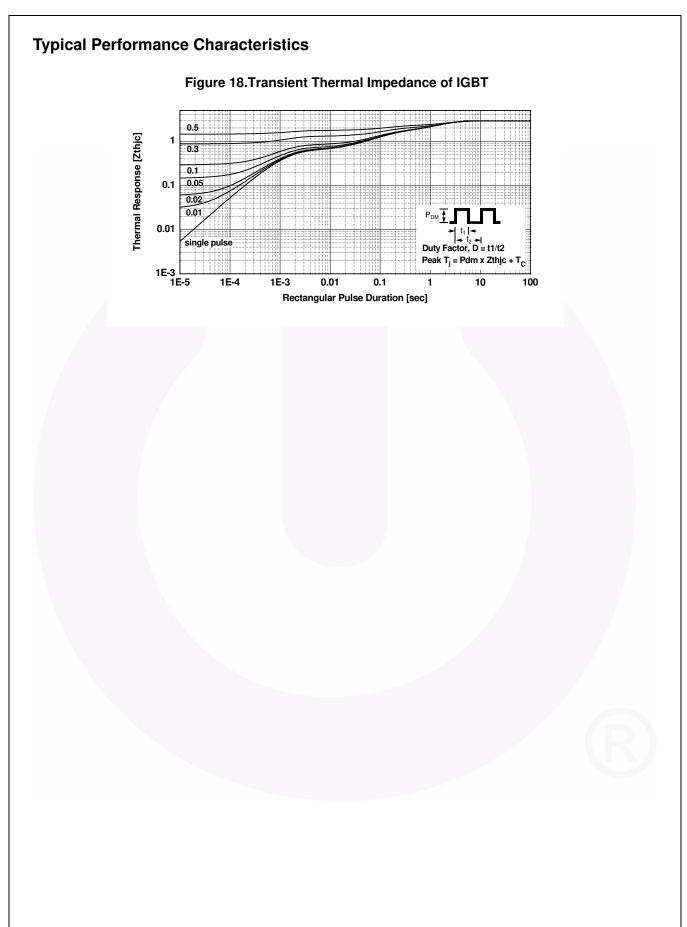
6.0

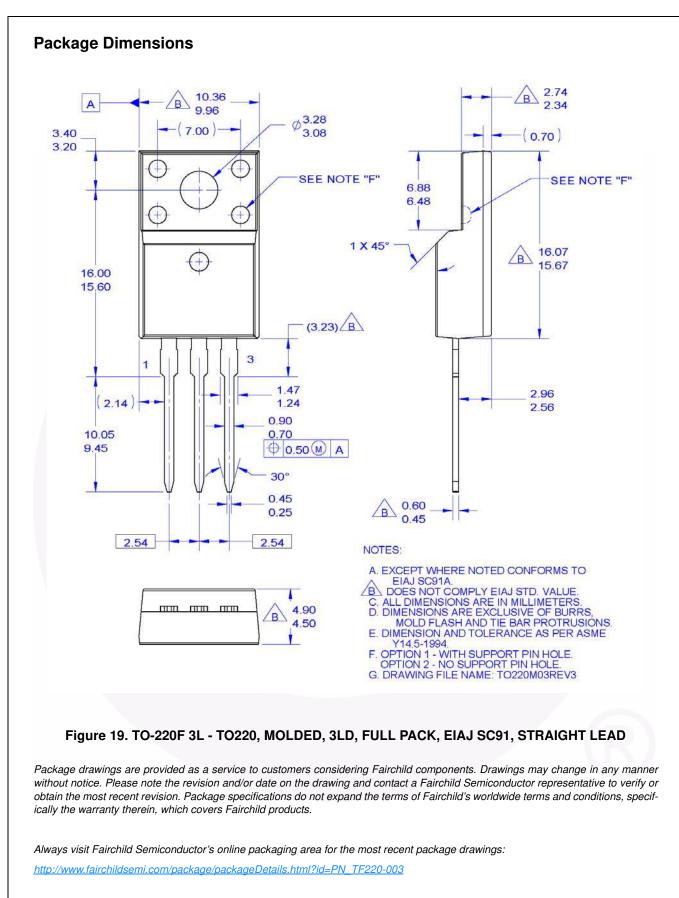


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330 V PDP Trench IGBT

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